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THERMAL CHARACTERISTICS

Operating and Storage Temperature Range

Thermal Resistance, Junction-to-Case

Thermal Resistance, Junction-to-Ambient (Note 1a)

(Note 1)

T_J,T_{STG}

 $\mathsf{R}_{\theta \mathsf{JA}}$

°C

°C/W

°C/W

-55 to 150

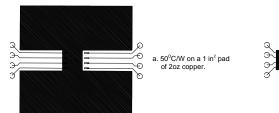
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Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$		-30			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = -250 µA, Referenced	to 25 °C		-22		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 V, V_{GS} = 0 V$				-1	μA
			T _J = 55°C			-10	μA
GSSF	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$				100	nA
GSSR	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				-100	nA
ON CHARAG	CTERISTICS (Note 2)						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1	-1.7	-3	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to $25 \ ^{\circ}\text{C}$			4.3		mV/°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -11 \text{ A}$			0.011	0.014	Ω
			T_ =125°C		0.016	0.023	
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -9 \text{ A}$			0.015	0.02	
D(ON)	On-State Drain Current	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$		-50			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -11 \text{ A}$			32		S
DYNAMIC C	HARACTERISTICS						
C _{iss}	Input Capacitance	$V_{DS} = -15 V, V_{GS} = 0 V,$			3000		pF
C _{oss}	Output Capacitance	f = 1.0 MHz			870		pF
C _{rss}	Reverse Transfer Capacitance				360		pF
SWITCHING	CHARACTERISTICS (Note 2)						-
t _{D(on)}	Turn - On Delay Time	V_{DS} = -15 V, I _D = -1 A			12	22	ns
т	Turn - On Rise Time	V_{GEN} = -10 V, R_{GEN} = 6 Ω			16	27	ns
D(off)	Turn - Off Delay Time				50	80	ns
f	Turn - Off Fall Time				100	140	ns
З ^а	Total Gate Charge	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -11 \text{ A},$			30	42	nC
⊋ _{gs}	Gate-Source Charge	V_{GS} = -5 V			9		nC
ସ _{gd}	Gate-Drain Charge				11		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MAXIM	JM RATINGS					
s	Maximum Continuous Drain-Source Diode Forward Current					-2.1	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = -2.1 A$ (Not	e 2)		-0.72	-1.2	V

Notes:

1. R_{g,M} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{g,C} is guaranteed by design while R_{gCA} is determined by the user's board design.

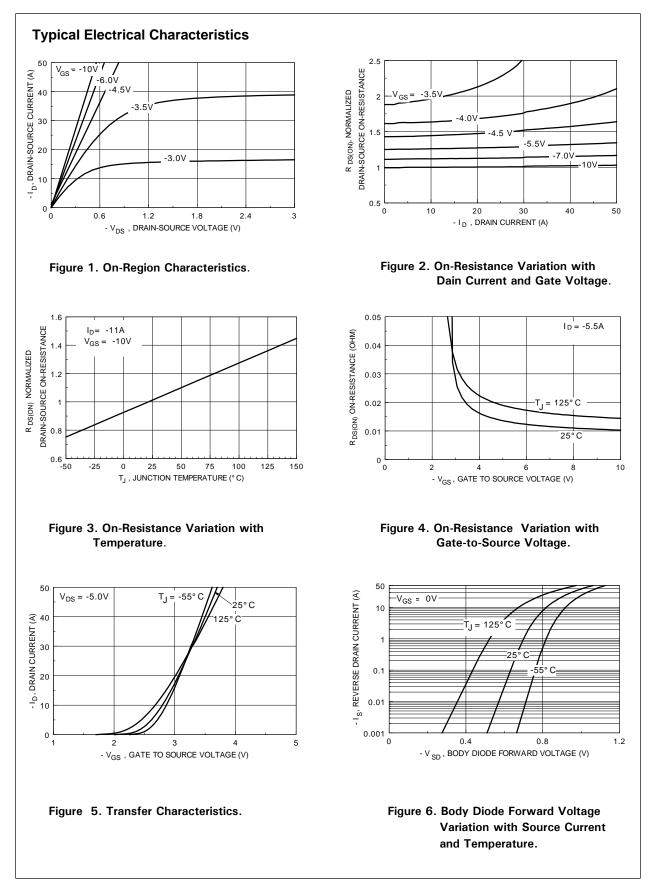




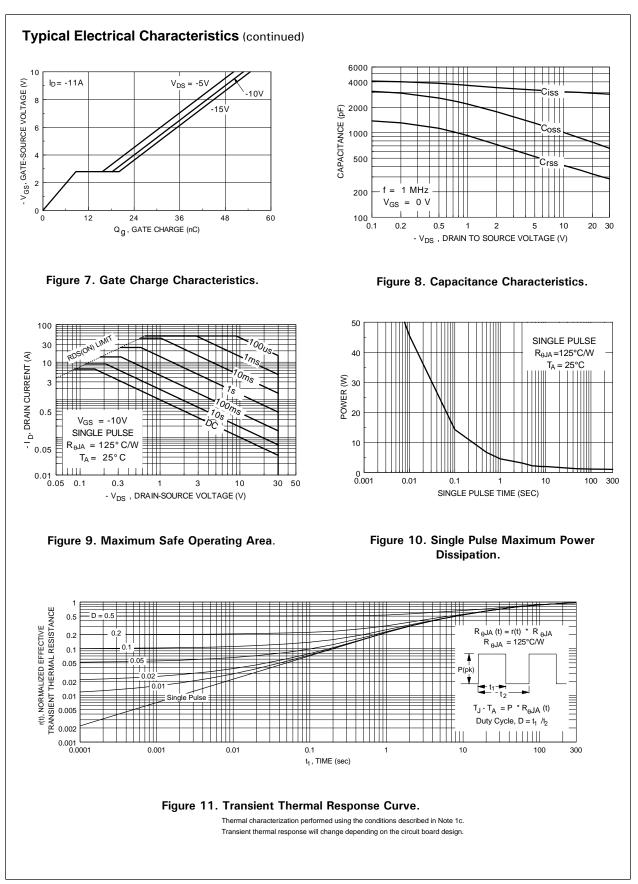
b. 105°C/W on a 0.04 in² pad of 2oz copper.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width $\underline{<}$ 300 $\!\mu s,$ Duty Cycle $\underline{<}$ 2.0%.



FDS6675 Rev.C2



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